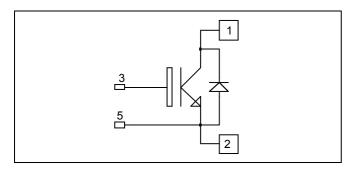


Single switch Trench + Field Stop IGBT3 Power Module



$$V_{CES} = 1700V$$

 $I_{C} = 400A$ @ $Tc = 80$ °C

Application

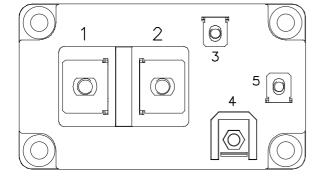
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- M6 connectors for power
- M4 connectors for signal
- High level of integration

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant



Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1700	V
I_{C}	Continuous Collector Current	$T_C = 25^{\circ}C$	800	
	Continuous Conector Current	$T_C = 80$ °C	400	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	800	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	2080	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	800A@1650V	

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				5	mA
V _{CE(sat)}	Collector Emitter saturation Voltage		$T_j = 25$ °C		2.0	2.4	V
				2.4		·	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 16 \text{ mA}$		5.2	5.8	6.4	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V$, $V_{CE} = 0V$				400	nA

Dynamic Characteristics

·	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V, V_{CE} = 25V$		33		nF
C_{res}	Reverse Transfer Capacitance	f = 1MHz		1.2		Ш
Q_{G}	Gate charge	V _{GE} =±15V, I _C =400A V _{CE} =900V		4.6		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (2:	5°C)	250		ns
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$		100		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 900V$ $I_{C} = 400A$		850		
T_{f}	Fall Time	$R_G = 3.6\Omega$		120		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (12	25°C)	300		ns
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$		100		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 900V$ $I_{C} = 400A$		1000		
$T_{\rm f}$	Fall Time	$R_G = 3.6\Omega$		200		
Eon	Turn On Energy	$\begin{vmatrix} V_{GE} = \pm 15V \\ V_{Bus} = 900V \end{vmatrix} T_j = 12$	5°C	135		mJ
E_{off}	Turn Off Energy	$\begin{bmatrix} I_C = 400A \\ R_G = 3.6\Omega \end{bmatrix} T_j = 12$	5°C	125		1117
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 1000$ $t_p \le 10 \mu s$; $T_i = 125 ^{\circ} C$	0V	1600		A

Reverse diode ratings and characteristics

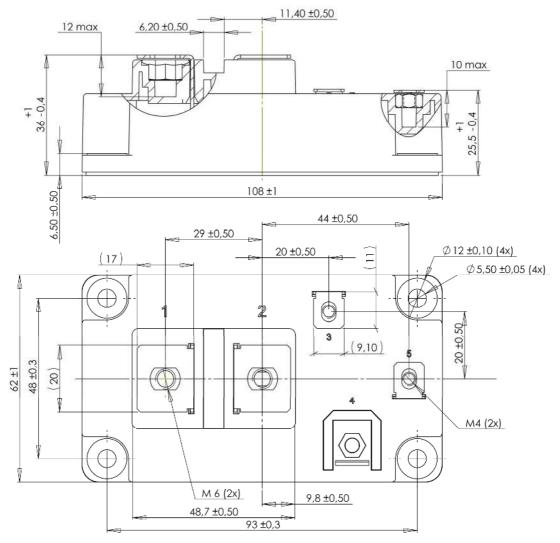
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1700			V
I_{RRM}	Maximum Reverse Leakage Current	V _R =1700V	$T_i = 25$ °C $T_i = 125$ °C			750 1000	μΑ
I_{F}	DC forward current		Tc=80°C		400		A
V_{F}	Diode Forward Voltage	$I_F = 400A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$		1.8	2.2	V
V _F	Diode Forward Voltage		$T_{i} = 125^{\circ}C$		1.9		
E_{rr}	E _{rr} Reverse Recovery Energy		$T_i = 25^{\circ}C$		50		mJ
Lit	Reverse Recovery Energy	1001	$T_i = 125$ °C		96		1113
+	Reverse Recovery Time	$I_F = 400A$	$T_i = 25^{\circ}C$		420		ns
ι _{rr}	t_{rr} Reverse Recovery Time $V_R = 900V$ $di/dt = 4200A/us$	$T_i = 125$ °C		525		115	
	Q _{rr} Reverse Recovery Charge	αι/αι 1200/1/μ3	$T_j = 25^{\circ}C$		100		C
Qrr		$T_j = 125$ °C		170		μC	



Thermal and package characteristics

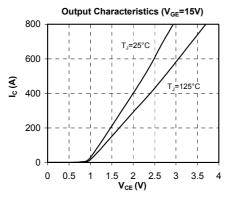
Symbol	Characteristic		Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance	IGBT			0.06	°C/W
KthJC		Diode			0.08	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		4000			V
T_{J}	Operating junction temperature range		-40		150	
T_{STG}	Storage Temperature Range Operating Case Temperature		-40		125	°C
$T_{\rm C}$			-40		125	
Torque	Mounting torque	M6	3		5	N.m
		M4	1		2	18.111
Wt	Package Weight				350	g

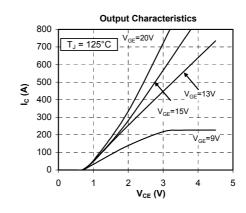
D4 Package outline (dimensions in mm)

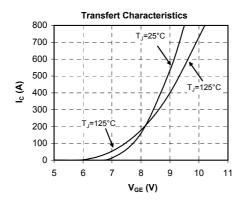


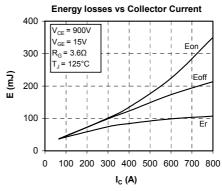


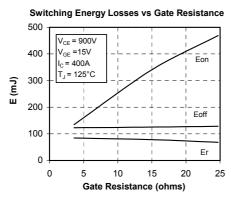
Typical Performance Curve

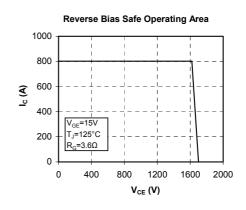


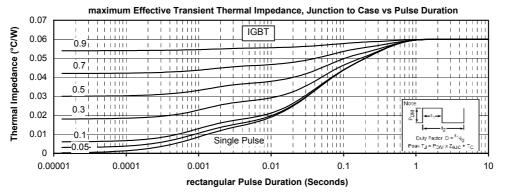




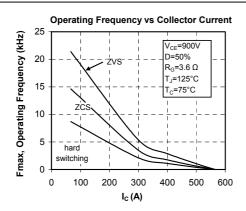


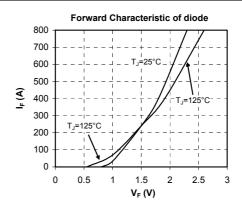


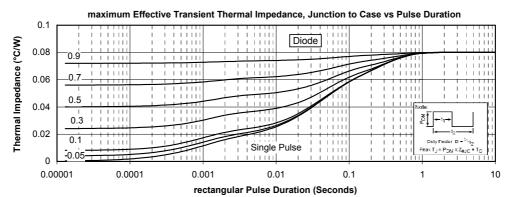














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